Preferred Device

Surface Mount Schottky Power Rectifier

This device employs the Schottky Barrier principle in a large area metal—to—silicon power diode. State—of—the—art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes, in surface mount applications where compact size and weight are critical to the system. Typical applications are AC—DC and DC—DC converters, reverse battery protection, and "ORing" of multiple supply voltages and any other application where performance and size are critical.

Features

- Very Low V_F Accompanied by Low I_R
- 1st in the Market Place with a 10 V_R Schottky Rectifier
- Small Compact Surface Mountable Package with J-Bend Leads
- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- Designed for Low Leakage
- Excellent Ability to Withstand Reverse Avalanche Energy Transients
- Guard-Ring for Stress Protection
- Pb-Free Package is Available

Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 217 mg (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Notch in Plastic Body Indicates Cathode Lead
- ESD Ratings: Machine Model = C

Human Body Model = 3B

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	10	V
Average Rectified Forward Current (@ T _L = 130°C)	I _O	4.0	Α
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	250	A
Operating Junction Temperature	TJ	-65 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



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SCHOTTKY BARRIER RECTIFIERS 4.0 AMPERES, 10 VOLTS



SMC CASE 403 PLASTIC

MARKING DIAGRAM



B4E1 = Specific Device Code A = Assembly Location Y = Year

WW = Work Week
■ Pb–Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MBRS410ET3	SMC	2500/Tape & Reel
MBRS410ET3G	SMC (Pb-Free)	2500/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	5 mm x 5 mm (Note 2)	1 Inch x 1/2 inch	Unit
Thermal Resistance, Junction-to-Lead Thermal Resistance.	$R_{ heta JL}$	12	7.0	°C/W
Junction-to-Ambient	$R_{ heta JA}$	109	59	

ELECTRICAL CHARACTERISTICS

Maximum Instantaneous Forward Voltage (Note 1)	V _F	T _J = 25°C	T _J = 100°C	V
$(I_F = 2.0 \text{ A})$ $(I_F = 4.0 \text{ A})$ $(I_F = 8.0 \text{ A})$		0.475 0.500 0.525	0.370 0.395 0.430	
Maximum Instantaneous Reverse Current (Note 1)	I _R	T _J = 25°C	T _J = 100°C	μΑ
(Rated dc Voltage, $V_R = 5.0 \text{ V}$) (Rated dc Voltage, $V_R = 10 \text{ V}$)		50 150	2000 4000	

- 1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
- 2. Mounted with Minimum Recommended Pad Size, PC Board FR4.

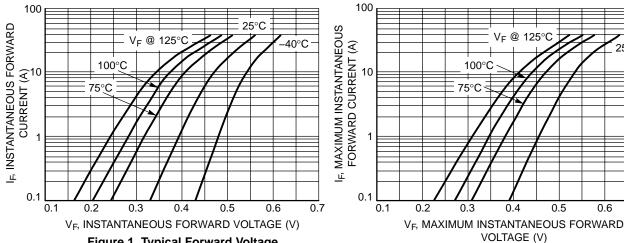


Figure 1. Typical Forward Voltage

Figure 2. Maximum Forward Voltage

0.6

0.7

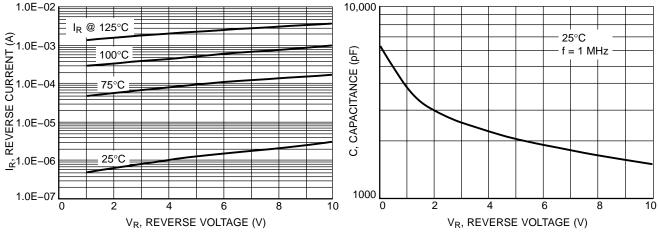
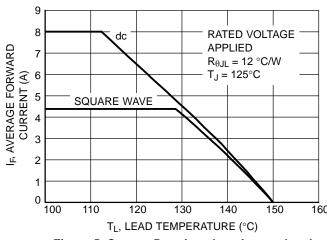


Figure 3. Typical Reverse Current

Figure 4. Typical Capacitance



3.5 NO IE A SOLUTION OF THE S

Figure 5. Current Derating, Junction-to-Lead

Figure 6. Forward Power Dissipation

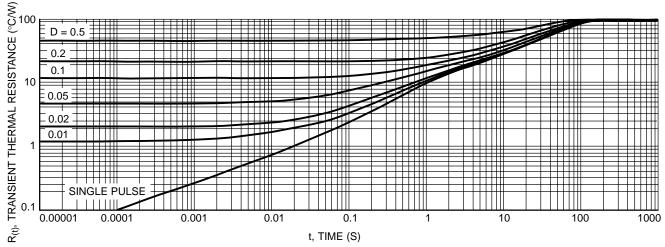


Figure 7. Thermal Response, Junction-to-Ambient (min pad)

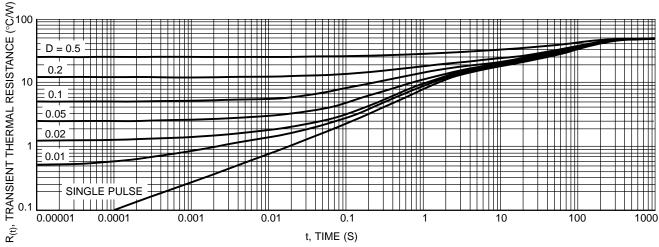
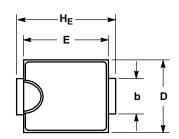


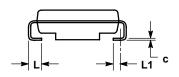
Figure 8. Thermal Response, Junction-to-Ambient (1 inch pad)

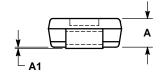
PACKAGE DIMENSIONS

SMC

PLASTIC PACKAGE CASE 403-03 ISSUE E





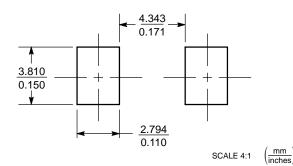


NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P.
- 403-01 THRU -02 OBSOLETE, NEW STANDARD 403-03

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.90	2.13	2.41	0.075	0.084	0.095
A1	0.05	0.10	0.15	0.002	0.004	0.006
b	2.92	3.00	3.07	0.115	0.118	0.121
С	0.15	0.23	0.30	0.006	0.009	0.012
D	5.59	5.84	6.10	0.220	0.230	0.240
E	6.60	6.86	7.11	0.260	0.270	0.280
HE	7.75	7.94	8.13	0.305	0.313	0.320
L	0.76	1.02	1.27	0.030	0.040	0.050
L1		0.51 REF	-	0.020 REF		

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D

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